

**ELECTRODE LINE STRUCTURE HAVING FINE LINE WIDTH
AND METHOD OF FORMING THE SAME**

Abstract of the Disclosure

5 In an electrode line structure of a semiconductor device and a method for forming
the same, the electrode line structure comprises a semiconductor substrate, and
electrode lines, which are formed on the semiconductor substrate, and have an inclined
end in the long axis direction. The electrode lines each include a first line unit, which
substantially functions as an electrode line, a second line unit, which has an inclined
10 end in the long axis direction and is separated from the first line unit by a predetermined
distance, and an insulating plug, which is interposed between the first line unit and the
second line unit and electrically insulates the first line unit from the second line unit.

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